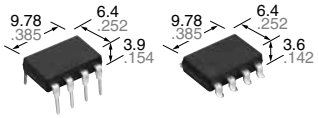
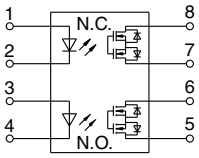
Both 1 Form A and 1 Form B contacts incorporated in a compact DIP8-pin with low on-resistance

PhotoMOS® HE 1 Form A & 1 Form B (AQW654)



(Height includes standoff)

mm inch



RoHS compliant

FEATURES

1. Applicable for 1 Form A and 1 Form B use as well as two independent 1 Form A and 1 Form B use

2. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

3. High sensitivity and low on-resistance

Can control max. 0.16 A load current with 5 mA input current. Low on-resistance of max. 11 Ω. (in case of using only 1 channel)

4. Low-level off state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- High-speed inspection machines
- Data communication equipment
- Telephone equipment
- Sensing equipment

TYPES

	Output rating*		Package	Part No.				Packing quantity	
				Through hole terminal	Surface-mount terminal				
	Load voltage	Load current		Tube packing style		Tape and reel packing style		Tube	Tape and reel
						Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side		
AC/DC dual use	400 V	120 mA	DIP8-pin	AQW654	AQW654A	AQW654AX	AQW654AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs

*Indicate the peak AC and DC values.
Note: The surface mount terminal indicator “A” and the packing style indicator “X” or “Z” are not marked on the device.

RATING

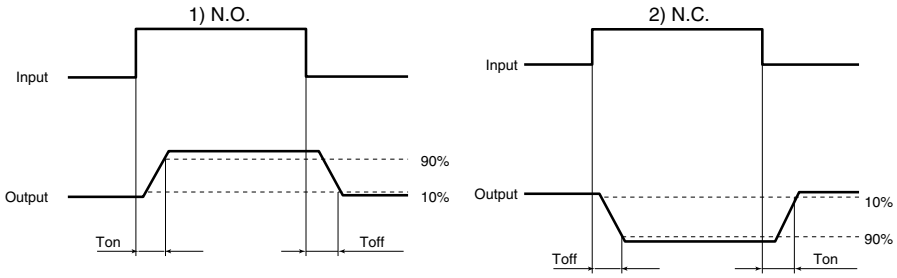
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW654(A)	Remarks
Input	LED forward current	I_F	50 mA	
	LED reverse voltage	V_R	5 V	
	Peak forward current	I_{FP}	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}	75 mW	
Output	Load voltage (peak AC)	V_L	400 V	
	Continuous load current	I_L	0.12A (0.16 A)	Peak AC, DC ( ): in case of using only 1 channel)
	Peak load current	I_{peak}	0.36 A	100 ms (1 shot), V_L = DC
	Power dissipation	P_{out}	800 mW	
Total power dissipation		P_T	850 mW	
I/O isolation voltage		V_{iso}	1,500 Vrms	
Ambient temperature	Operating	T_{opr}	–40 to +85°C –40 to +185°F	(Non-icing at low temperatures)
	Storage	T_{stg}	–40 to +100°C –40 to +212°F	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW654(A)	Condition
Input	LED operate current	Typical	I_{Fon} (N.O.) I_{Foff} (N.C.)	0.9 mA	I_L = Max.
		Maximum		3 mA	
	LED reverse current	Minimum	I_{Foff} (N.O.) I_{Fon} (N.C.)	0.4 mA	I_L = Max.
		Typical		0.8 mA	
	LED dropout voltage	Typical	V_F	1.25 V (1.14 V at I_F = 5 mA)	I_F = 50 mA
		Maximum		1.5 V	
Output	On resistance	Typical	R_{on}	11 Ω	I_F = 5 mA (N.O.) I_F = 0 mA (N.C.) I_L = Max. Within 1 s
		Maximum		16 Ω	
	Off state leakage current	Maximum	I_{Leak}	1 μA	I_F = 0 mA (N.O.) I_F = 5 mA (N.C.) V_L = Max.
Transfer characteristics	Operate time*	Typical	T_{on} (N.O.) T_{off} (N.C.)	0.8 ms (N.O.) 1.2 ms (N.C.)	I_F = 0 mA → 5 mA I_L = Max.
		Maximum		2 ms	
	Reverse time*	Typical	T_{off} (N.O.) T_{on} (N.C.)	0.04 ms (N.O.) 0.36 ms (N.C.)	I_F = 5 mA → 0 mA I_L = Max.
		Maximum		1 ms	
	I/O capacitance	Typical	C_{iso}	0.8 pF	f = 1 MHz V_B = 0 V
		Maximum		1.5 pF	
	Initial I/O isolation resistance	Minimum	R_{iso}	1,000 MΩ	500 V DC

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item		Symbol	Number of used channels	Min.	Max.	Unit
LED current		I_F		5	30	mA
AQW654(A)	Load voltage (Peak AC)	V_L		—	320	V
	Continuous load current	I_L	1ch 2ch	—	0.16 0.12	A

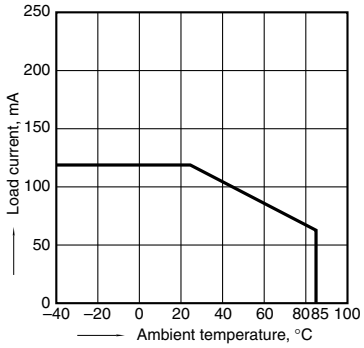
■ **These products are not designed for automotive use.**
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

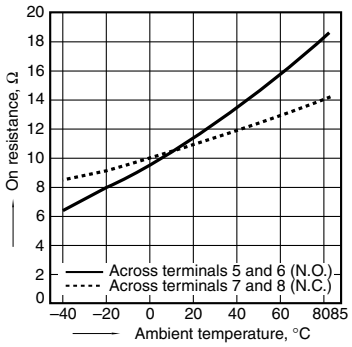
Allowable ambient temperature: –40 to +85°C
–40 to +185°F

When using 2 channels



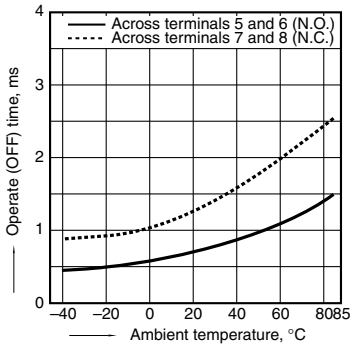
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



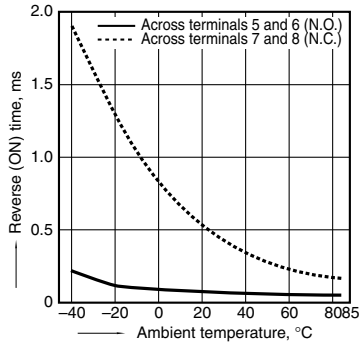
3. Operate time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



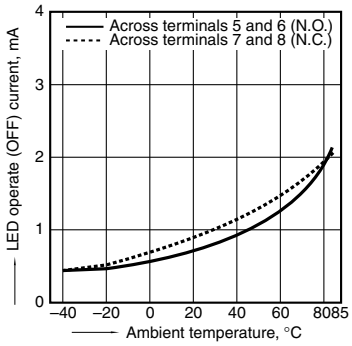
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



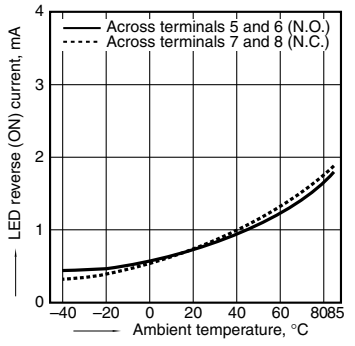
5. LED operate current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



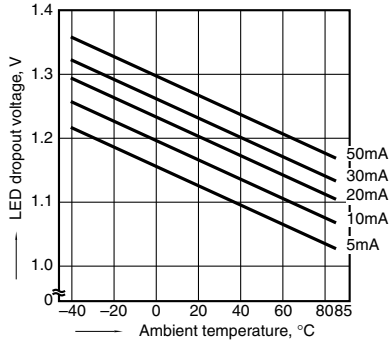
6. LED reverse current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



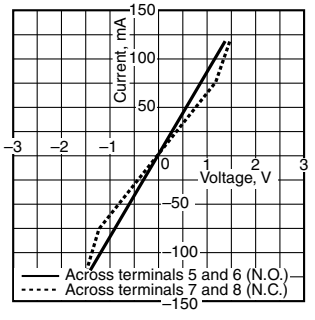
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



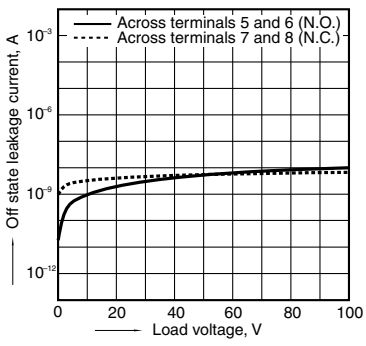
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



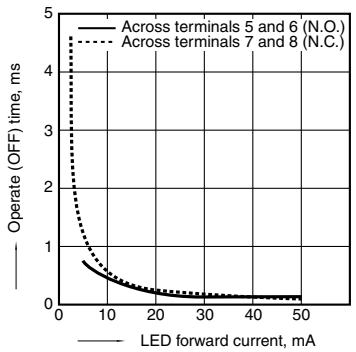
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



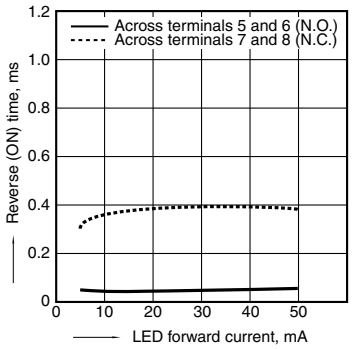
10. Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



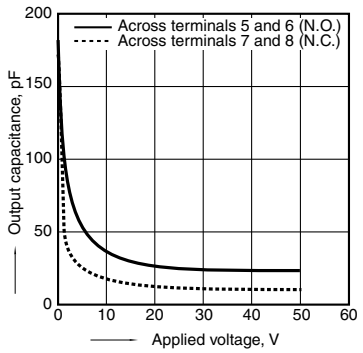
11. Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz;
Ambient temperature: 25°C 77°F



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